NSN 5961-00-021-9048

Transistor - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.350 inches

Overall Diameter:

0.875 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Internal Junction Configuration:

Npn

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

500.0 collector to emitter voltage/static/base open and 700.0 collector to emitter voltage, dc with specified circuit between base and emitter

Current Rating Per Characteristic:

2.00 amperes base current, dc and 3.50 amperes collector current, dc

Power Rating Per Characteristic:

150.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Precious Material And Location:

Terminal surface gold

Precious Material:

Gold

Terminal Type And Quantity:

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0